

## FEATURES

- ✧ High current capability, low forward voltage
- ✧ Excellent high temperature stability
- ✧ Low power loss, and high efficiency
- ✧ High forward surge capability
- ✧ RoHS compliant, and Halogen free

## MACHANICAL DATA

- ✧ Case: TO-277B small outline plastic package
- ✧ Terminal: Matte tin plated, solderable per MIL-STD-750, Method 2026
- ✧ Molding Compound Flammability Rating:UL94-0
- ✧ High temperature soldering guaranteed: 260°C /10second
- ✧ Packed with FRP substrate and epoxy underfilled

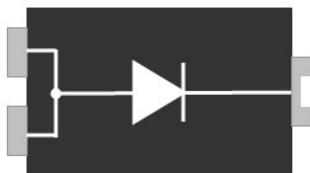
## ORDERING INFORMATION

- ✧ Device: GSD10N45SL
- ✧ Package: TO-277B
- ✧ Marking: 10N45
- ✧ Material: Halogen free
- ✧ Packing: Tape & 13" Reel
- ✧ Quantity per reel: 5,000pcs

## APPLICATIONS

- ✧ Switching mode power supply applications
- ✧ Portable equipment battery applications
- ✧ High frequency rectification
- ✧ DC/DC converter
- ✧ Designed as bypass diodes for solar panels

## PIN CONFIGURATION



## PACKAGE OUTLINE

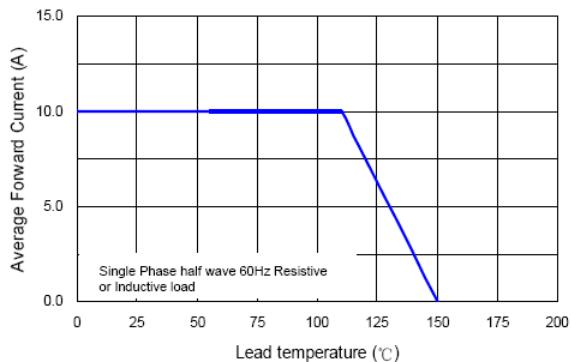
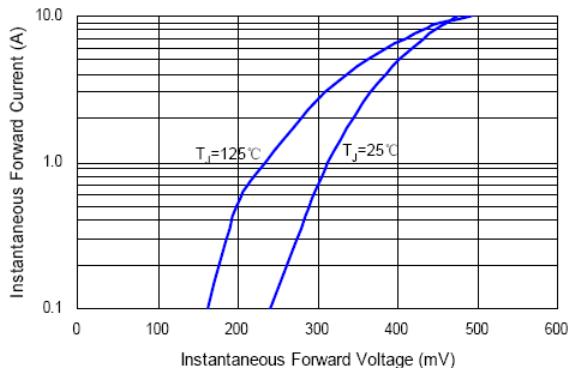
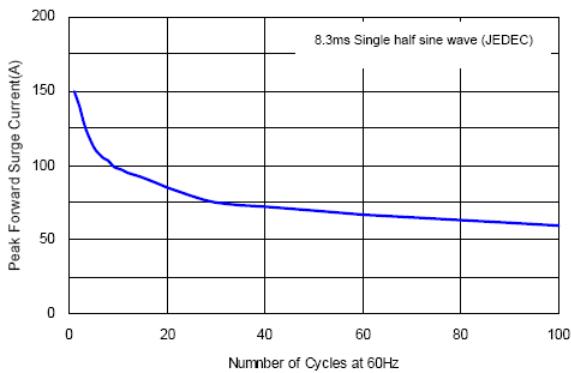
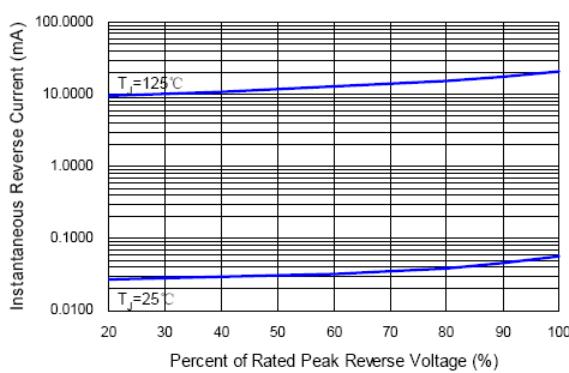
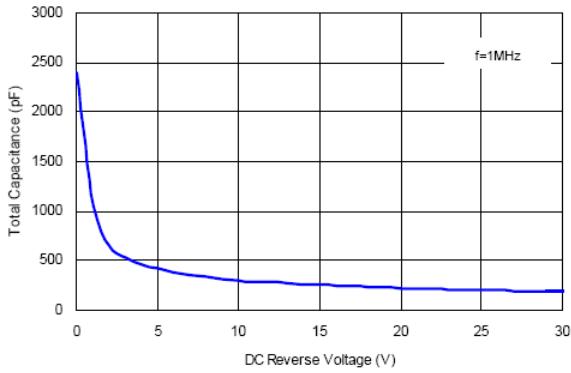


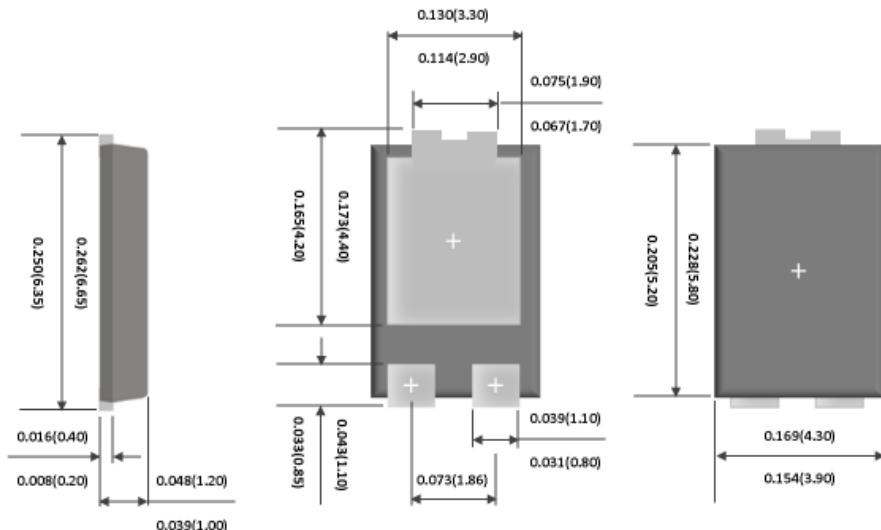
**ABSOLUTE MAXIMUM RATING (Tamb=25°C, unless otherwise specified)**

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	45	V
I <sub>F(AV)</sub>	Average Forward Current	10	A
I <sub>FSM</sub>	Peak Forward Surge Current, 8.3ms single half sine-wave	150	A
T <sub>J</sub> & T <sub>STG</sub>	Junction and Storage Temperature	-50~+150	°C

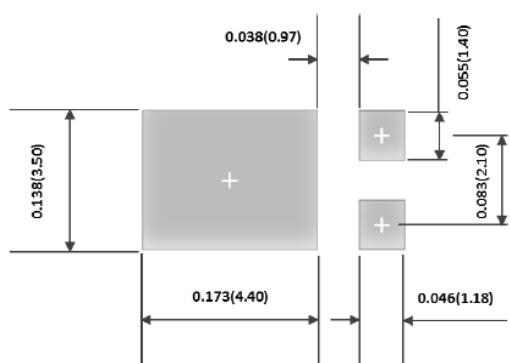
**ELECTRICAL CHARACTERISTICS (Tamb=25°C, unless otherwise specified)**

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 3A @ 25°C		0.37	0.40	V
		I <sub>F</sub> = 5A @ 25°C		0.40	0.45	V
		I <sub>F</sub> = 10A @ 25°C		0.48	0.52	V
		I <sub>F</sub> = 3A @ 125°C		0.28		V
		I <sub>F</sub> = 5A @ 125°C		0.34		V
		I <sub>F</sub> = 10A @ 125°C		0.45		V
V <sub>R</sub>	Reverse Breakdown Voltage	I <sub>R</sub> = 0.5mA	45			V
I <sub>R</sub>	Reverse Leakage Current	V <sub>R</sub> = 45V @ 25°C			0.20	mA
		V <sub>R</sub> = 45V @ 125°C		20		mA
C <sub>J</sub>	Junction Capacitance	f=1MHz, V <sub>R</sub> =4V		460		pF

**ELECTRICAL CHARACTERISTICS CURVE**
**Fig 1 Typical Forward Current Derating Curve**

**Fig 2 Typical Instantaneous Forward Characteristics**

**Fig 3 Max. Non-repetitive Forward Surge Current**

**Fig 4 Typical Reverse Characteristics**

**Fig 5 Total Capacitance vs. Reverse Voltage**


**TO-277B PACKAGE OUTLINE DIMENSIONS**


unit: mm

**FOOT PRINT RECOMMENDATION**


unit: mm

**MARKING CODE**


10N45	YYYY	XXX
Device name	Trace code	Date code
	XXXX	XX
		XX=month(01,02,03,04,... 11,12)
		X=year(2=2012,3=2013,4=2014...)